

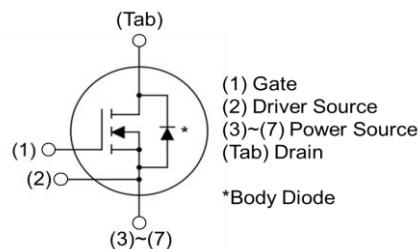
$V_{DSS}$	650V
$R_{DS(on)}$ (Typ.)	30m $\Omega$
$I_D^{*1}$	70A
$P_D$	267W

### ●Outline

TO-263-7L



### ●Inner circuit



Please note Driver Source and Power Source are not exchangeable. Their exchange might lead to malfunction.

### ●Packaging specifications

Type	Packing	Embossed tape
	Reel size (mm)	330
	Tape width (mm)	24
	Basic ordering unit (pcs)	1000
	Taping code	TL
	Marking	SCT3030AW7

### ●Application

- Solar inverters
- DC/DC converters
- Switch mode power supplies
- Induction heating
- Motor drives

### ●Absolute maximum ratings ( $T_{vj} = 25^\circ\text{C}$ unless otherwise specified)

Parameter	Symbol	Value	Unit
Drain - Source Voltage	$V_{DSS}$	650	V
Continuous Drain current	$I_D^{*1}$	70	A
	$I_D^{*1}$	50	A
Pulsed Drain current ( $T_c = 25^\circ\text{C}$ )	$I_{D,pulse}^{*2}$	175	A
Gate - Source voltage (DC)	$V_{GSS}$	-4 to +22	V
Gate - Source surge voltage ( $t_{surge} < 300\text{ns}$ )	$V_{GSS,surge}^{*3}$	-4 to +26	V
Recommended drive voltage	$V_{GS,op}^{*4}$	0 / +18	V
Virtual Junction temperature	$T_{vj}$	175	°C
Range of storage temperature	$T_{stg}$	-55 to +175	°C

●Electrical characteristics ( $T_{vj} = 25^\circ\text{C}$  unless otherwise specified)

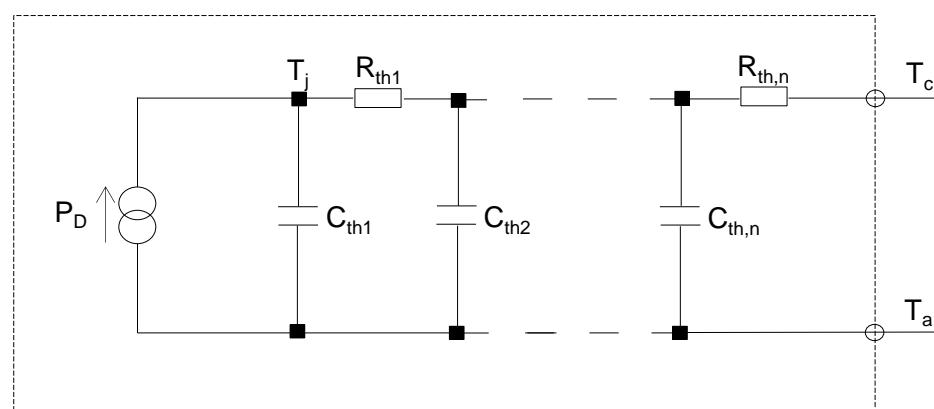
Parameter	Symbol	Conditions	Values			Unit
			Min.	Typ.	Max.	
Drain - Source breakdown voltage	$V_{(\text{BR})\text{DSS}}$	$V_{GS} = 0\text{V}, I_D = 1\text{mA}$	650	-	-	V
		$T_{vj} = 25^\circ\text{C}$	650	-	-	
Zero Gate voltage Drain current	$I_{\text{DSS}}$	$V_{GS} = 0\text{V}, V_{DS} = 650\text{V}$	-	1	10	$\mu\text{A}$
		$T_{vj} = 25^\circ\text{C}$	-	2	-	
Gate - Source leakage current	$I_{\text{GSS}+}$	$V_{GS} = +22\text{V}, V_{DS} = 0\text{V}$	-	-	100	$\text{nA}$
		$V_{GS} = -4\text{V}, V_{DS} = 0\text{V}$	-	-	-100	
Gate threshold voltage	$V_{GS(\text{th})}$	$V_{DS} = 10\text{V}, I_D = 13.3\text{mA}$	2.7	-	5.6	V
Static Drain - Source on - state resistance	$R_{\text{DS}(\text{on})}^{*5}$	$V_{GS} = 18\text{V}, I_D = 27\text{A}$	-	30	39	$\text{m}\Omega$
		$T_{vj} = 25^\circ\text{C}$	-	43	-	
Gate input resistance	$R_G$	f = 1MHz, open drain	-	7	-	$\Omega$

## ●Thermal resistance

Parameter	Symbol	Values			
		Min.	Typ.	Max.	
Thermal resistance, junction - case <sup>*6</sup>	$R_{\text{thJC}}$	-	0.44	0.56	K/W

## ●Typical Transient Thermal Characteristics

Symbol	Value	Unit	Symbol	Value	Unit
$R_{\text{th}1}$	$4.06 \times 10^{-2}$	K/W	$C_{\text{th}1}$	$7.06 \times 10^{-3}$	Ws/K
$R_{\text{th}2}$	$6.86 \times 10^{-2}$		$C_{\text{th}2}$	$2.59 \times 10^{-2}$	
$R_{\text{th}3}$	$3.31 \times 10^{-1}$		$C_{\text{th}3}$	$2.77 \times 10^{-2}$	



●Electrical characteristics ( $T_{vj} = 25^\circ\text{C}$  unless otherwise specified)

Parameter	Symbol	Conditions	Values			Unit
			Min.	Typ.	Max.	
Transconductance	$g_{fs}^{*5}$	$V_{DS} = 10\text{V}$ , $I_D = 27\text{A}$	-	9.4	-	S
Input capacitance	$C_{iss}$	$V_{GS} = 0\text{V}$ $V_{DS} = 500\text{V}$ $f = 1\text{MHz}$	-	1526	-	pF
Output capacitance	$C_{oss}$		-	89	-	
Reverse transfer capacitance	$C_{rss}$		-	42	-	
Effective output capacitance, energy related	$C_{o(er)}$	$V_{GS} = 0\text{V}$ $V_{DS} = 0\text{V to } 300\text{V}$	-	230	-	pF
Total Gate charge	$Q_g^{*5}$	$V_{DS} = 300\text{V}$ $I_D = 27\text{A}$ $V_{GS} = 18\text{V}$	-	104	-	nC
Gate - Source charge	$Q_{gs}^{*5}$		-	19	-	
Gate - Drain charge	$Q_{gd}^{*5}$		-	55	-	
Turn - on delay time	$t_{d(on)}^{*5}$	$V_{DS} = 400\text{V}$ $I_D = 27\text{A}$ $V_{GS} = 0\text{V}/+18\text{V}$ $R_G = 0\Omega$ , $L = 750\mu\text{H}$ $L_\sigma = 50\text{nH}$ , $C_\sigma = 10\text{pF}$ See Fig. 1-1.	-	7	-	ns
Rise time	$t_r^{*5}$		-	22	-	
Turn - off delay time	$t_{d(off)}^{*5}$		-	27	-	
Fall time	$t_f^{*5}$		-	21	-	
Turn - on switching loss	$E_{on}^{*5}$		-	159	-	$\mu\text{J}$
Turn - off switching loss	$E_{off}^{*5}$		-	87	-	

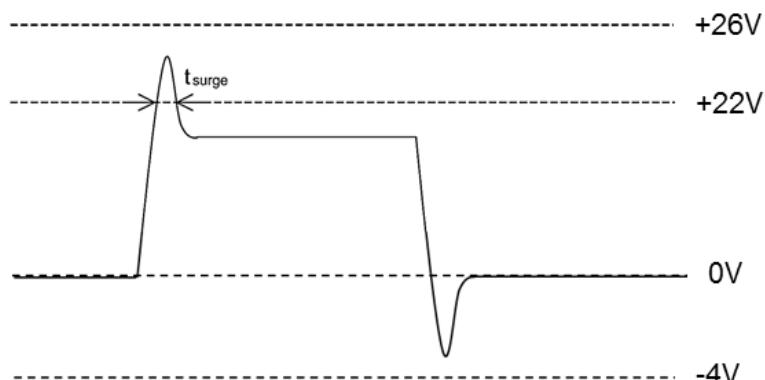
●Body diode electrical characteristics (Source-Drain) ( $T_{vj} = 25^\circ\text{C}$  unless otherwise specified)

Parameter	Symbol	Conditions	Values			Unit
			Min.	Typ.	Max.	
Body diode continuous, forward current	$I_S^{*1}$	$T_c = 25^\circ\text{C}$	-	-	70	A
Body diode direct current, pulsed	$I_{SM}^{*2}$		-	-	175	A
Forward voltage	$V_{SD}^{*5}$	$V_{GS} = 0\text{V}, I_S = 27\text{A}$	-	3.2	-	V
Reverse recovery time	$t_{rr}^{*5}$	$I_F = 27\text{A}$ $V_R = 400\text{V}$ $dI/dt = 2500\text{A}/\mu\text{s}$	-	28	-	ns
Reverse recovery charge	$Q_{rr}^{*5}$		-	702	-	nC
Peak reverse recovery current	$I_{rrm}^{*5}$	$L_\sigma = 50\text{nH}, C_\sigma = 10\text{pF}$ See Fig. 3-1, 3-2.	-	40	-	A

\*1 Limited by maximum  $T_{vj}$  and for Max.  $R_{thJC}$ .

\*2 PW  $\leq 10\mu\text{s}$ , Duty cycle  $\leq 1\%$

\*3 Example of acceptable  $V_{GS}$  waveform



Please note especially when using driver source that  $V_{GS\_surge}$  must be in the range of absolute maximum rating.

\*4 Please be advised not to use SiC-MOSFETs with  $V_{GS}$  below 13V as doing so may cause thermal runaway.

\*5 Pulsed

\*6 The case mentioned in this parameter is the bottom of leadframe located underneath the chip. Actual value of the  $R_{th(j-c)}$  is influenced by user's application design. The described value is only valid at the specific conditions such as JEDEC51-14.

### ●Electrical characteristic curves

Fig.1 Power Dissipation Derating Curve

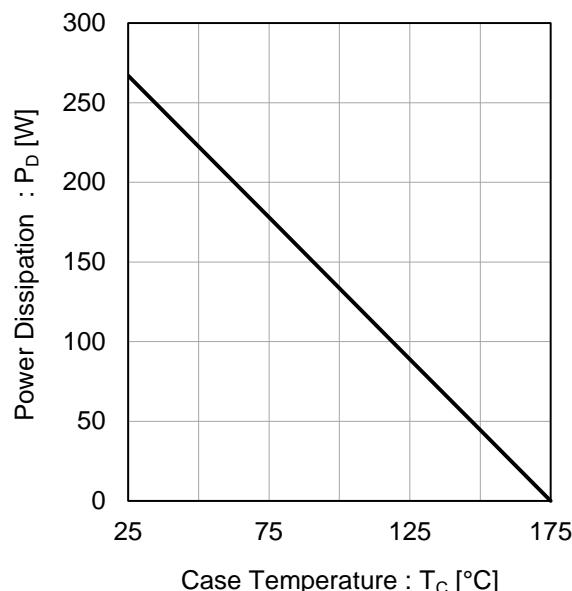


Fig.2 Maximum Safe Operating Area

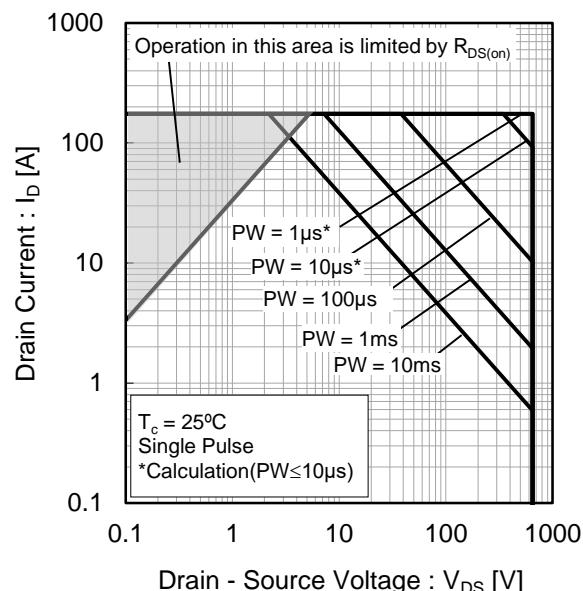
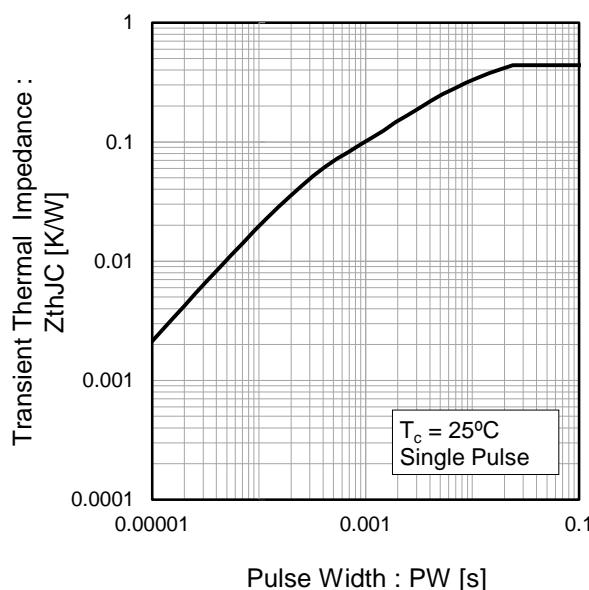


Fig.3 Typical Transient Thermal Impedance vs. Pulse Width



## ●Electrical characteristic curves

Fig.4 Typical Output Characteristics(I)

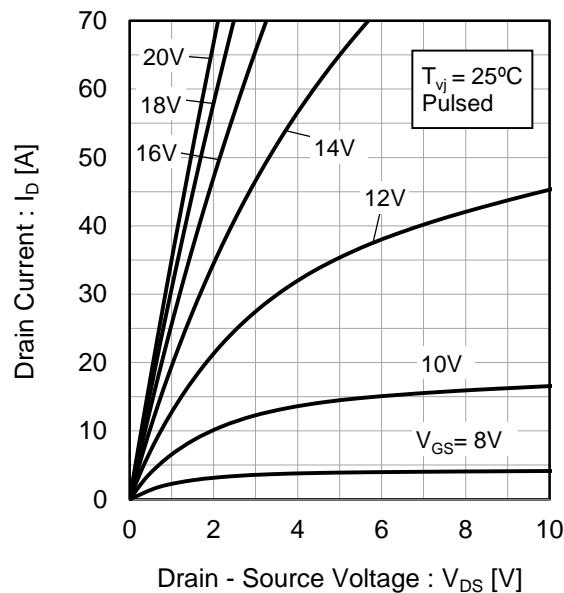
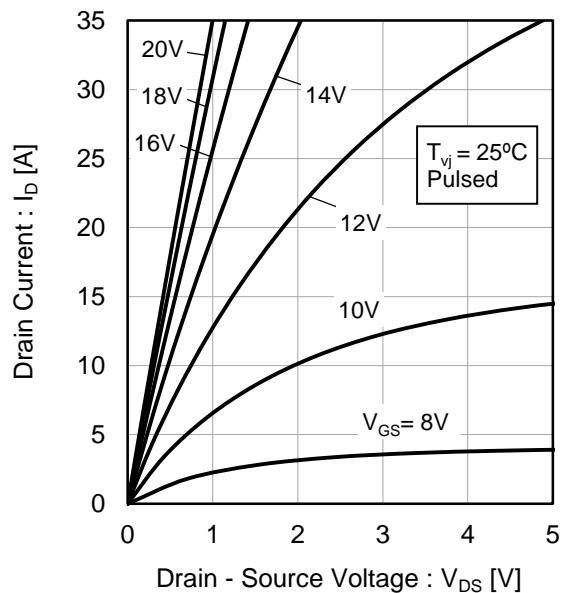
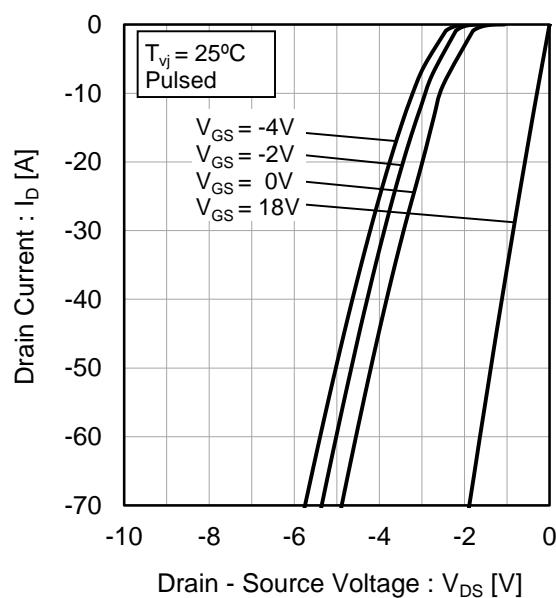


Fig.5 Typical Output Characteristics(II)

Fig.6  $T_{vj} = 25^\circ C$  3rd Quadrant Characteristics

## ●Electrical characteristic curves

Fig.7  $T_{vj} = 150^{\circ}\text{C}$  Typical Output Characteristics(I)

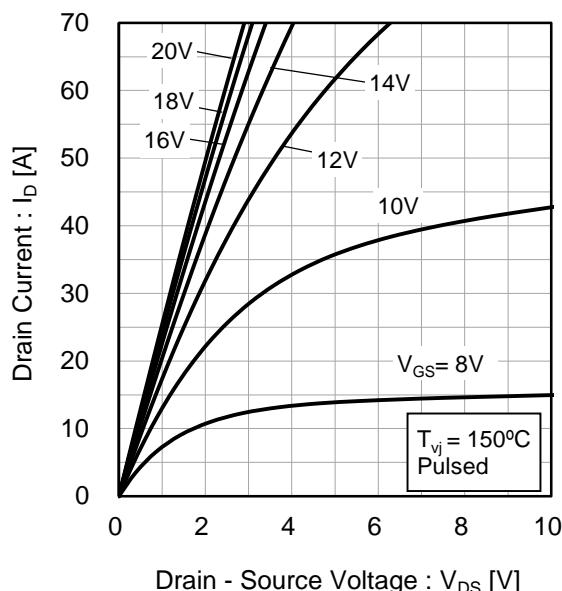


Fig.8  $T_{vj} = 150^{\circ}\text{C}$  Typical Output Characteristics(II)

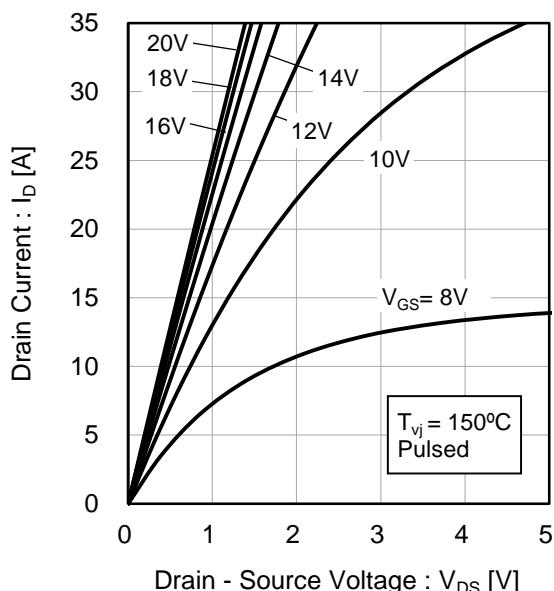


Fig.9  $T_{vj} = 150^{\circ}\text{C}$  3rd Quadrant Characteristics

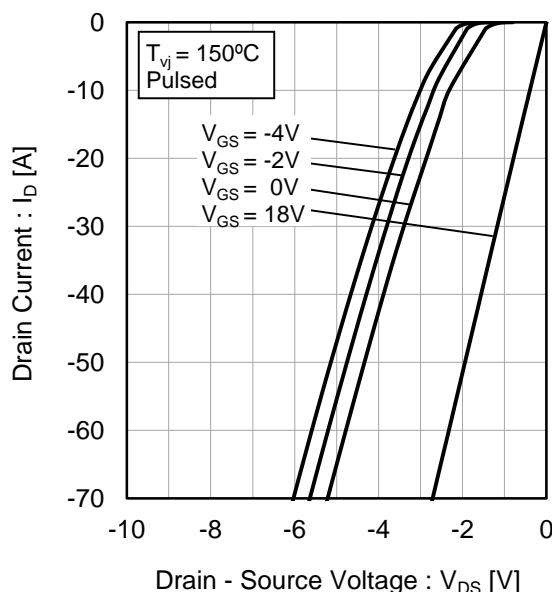
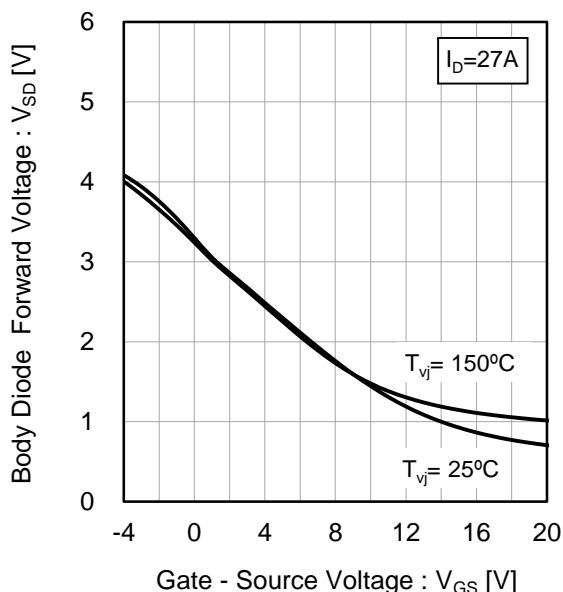


Fig.10 Body Diode Forward Voltage vs. Gate - Source Voltage



## ●Electrical characteristic curves

Fig.11 Typical Transfer Characteristics (I)

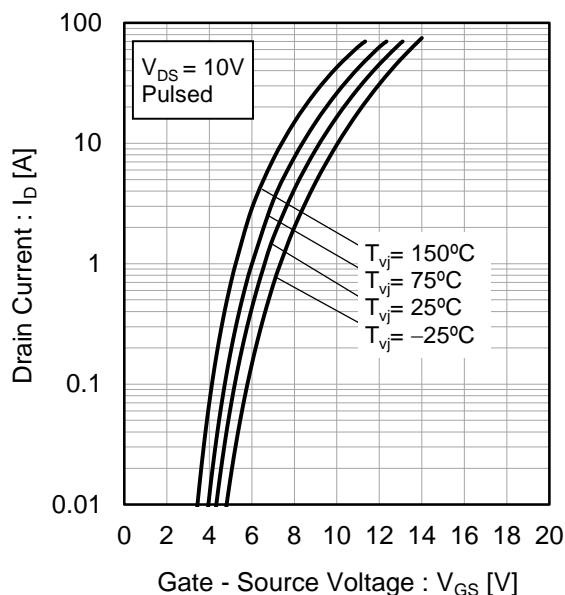


Fig.12 Typical Transfer Characteristics (II)

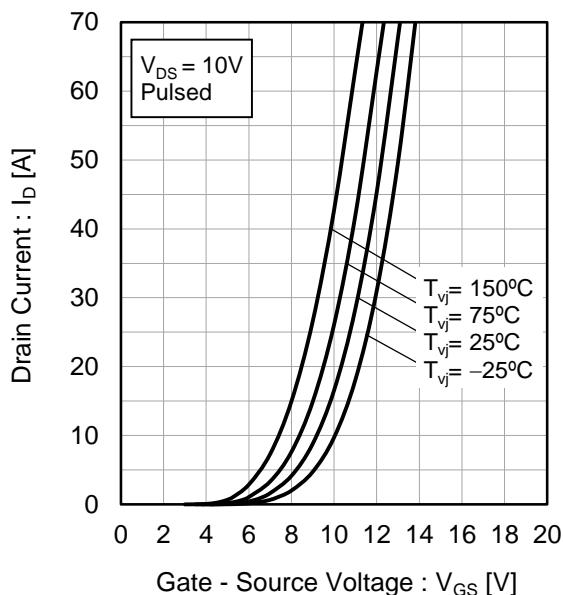


Fig.13 Gate Threshold Voltage vs. Virtual Junction Temperature

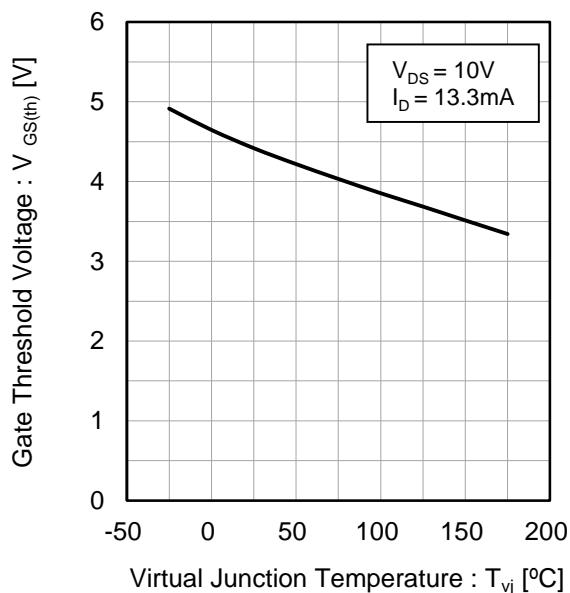
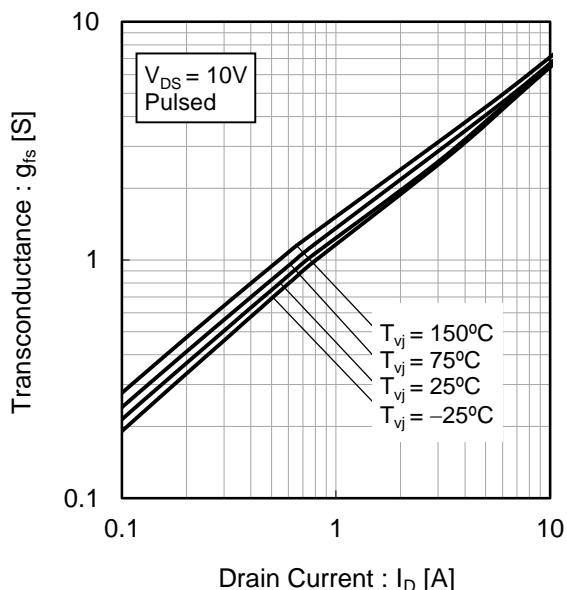


Fig.14 Transconductance vs. Drain Current



### ●Electrical characteristic curves

Fig.15 Static Drain - Source On - State  
Resistance vs. Gate - Source Voltage

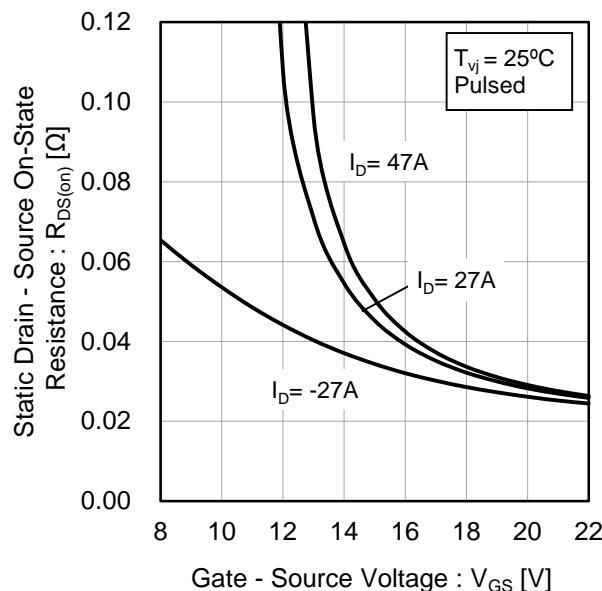


Fig.16 Static Drain - Source On - State  
Resistance vs. Virtual Junction Temperature

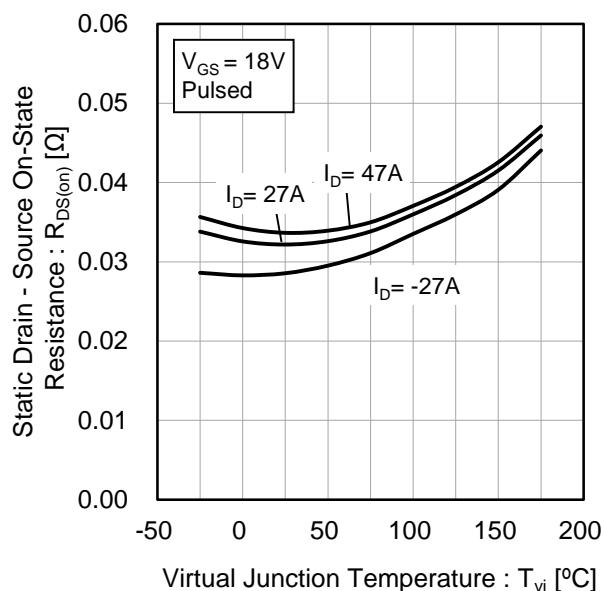


Fig.17 Static Drain - Source On - State  
Resistance vs. Drain Current

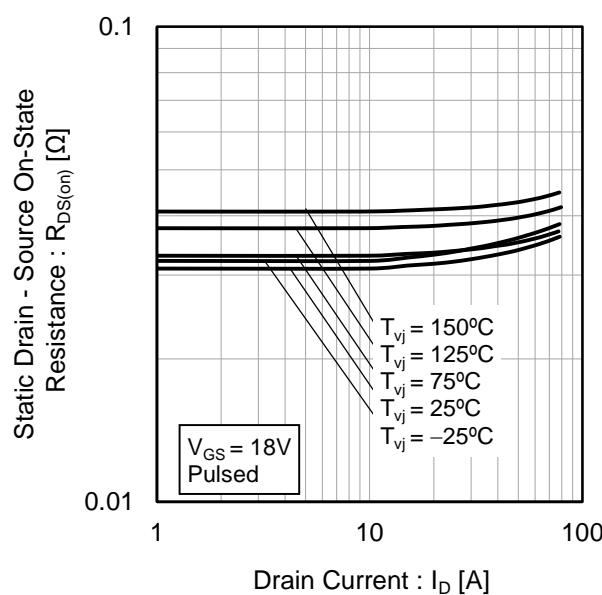
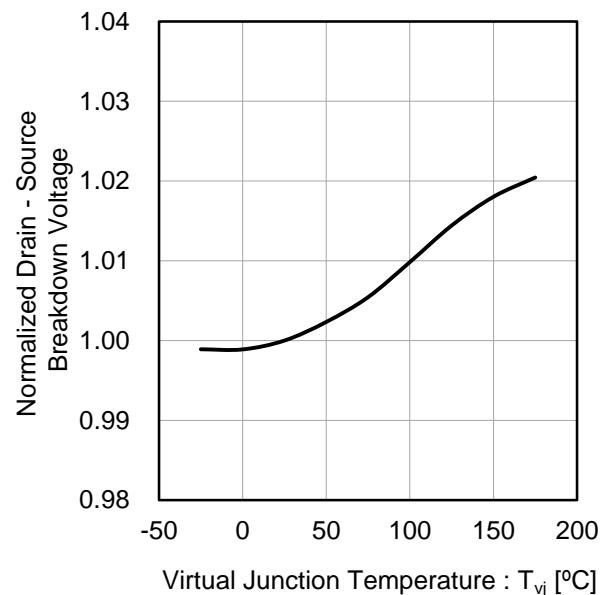


Fig.18 Normalized Drain - Source Breakdown  
Voltage vs. Virtual Junction Temperature



### ●Electrical characteristic curves

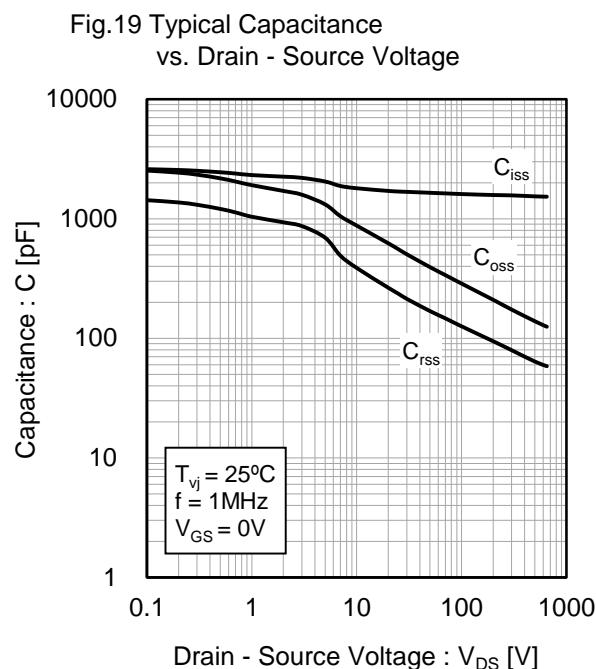
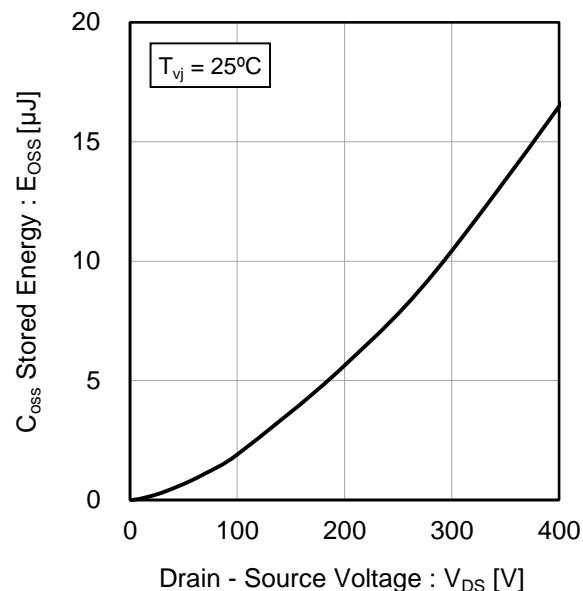
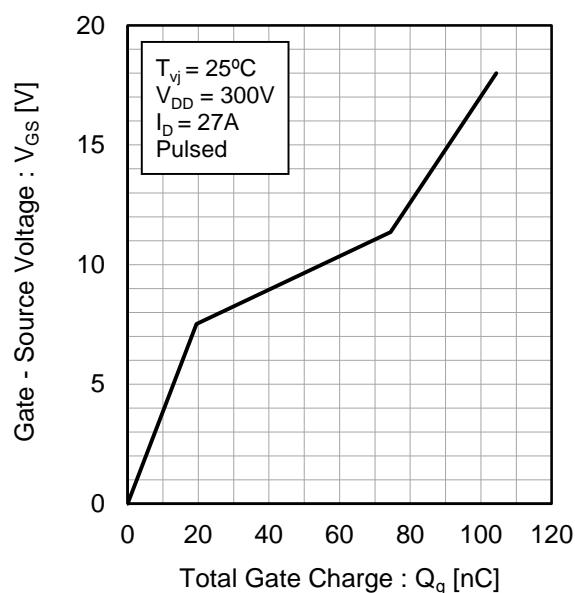
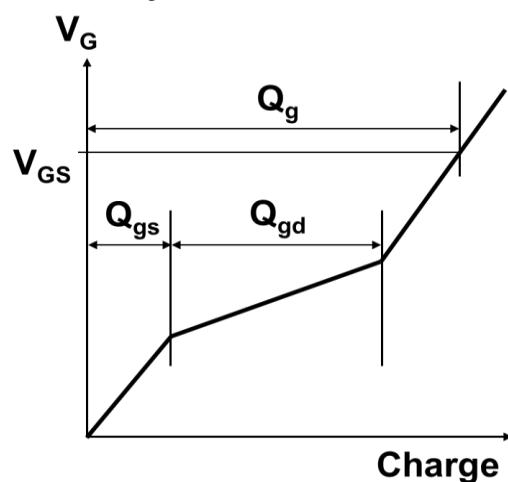
Fig.20  $C_{oss}$  Stored Energy

Fig.21 Dynamic Input Characteristics



\*Gate Charge Waveform



### ●Electrical characteristic curves

Fig.22 Typical Switching Time vs. External Gate Resistance

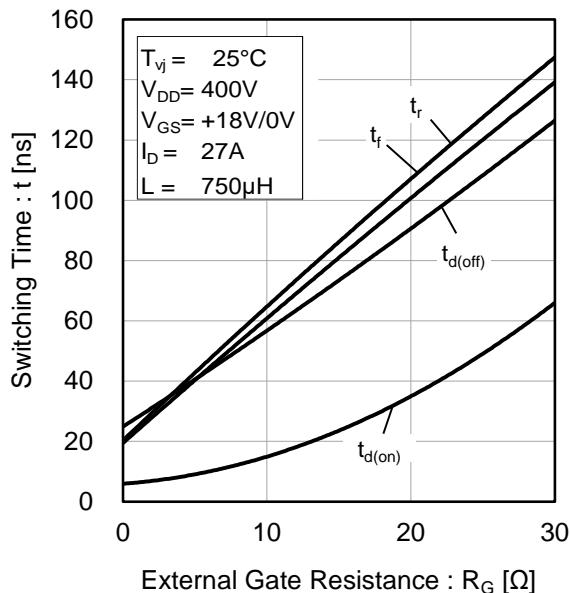


Fig.23 Typical Switching Loss vs. Drain - Source Voltage

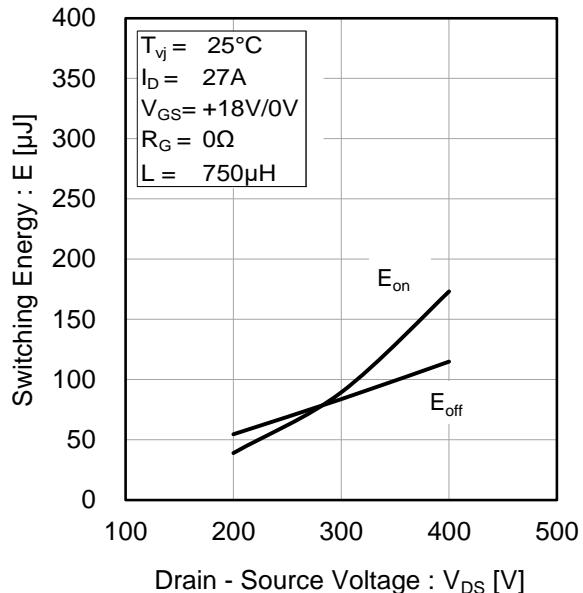


Fig.24 Typical Switching Loss vs. Drain Current

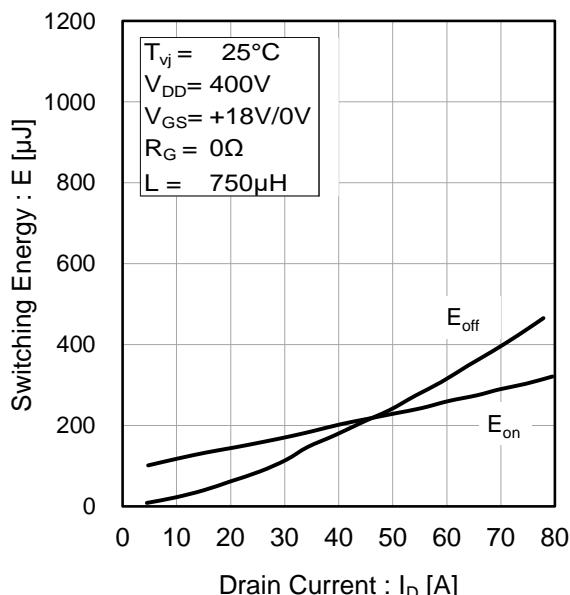
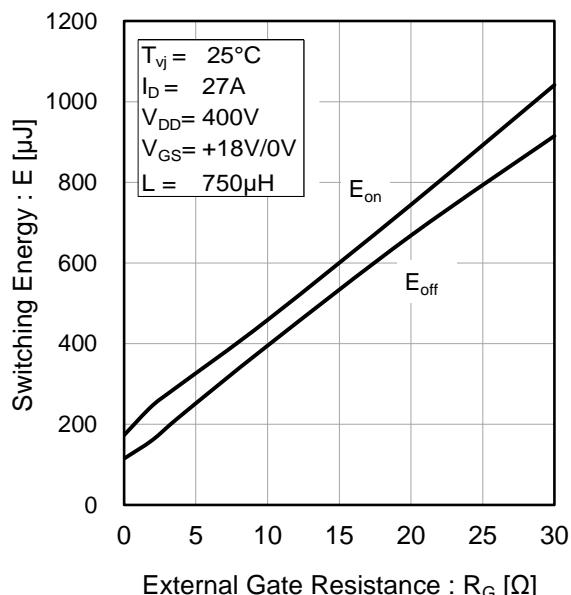


Fig.25 Typical Switching Loss vs. External Gate Resistance



## ● Measurement circuits and waveforms

Fig.1-1 Gate Charge Measurement Circuit

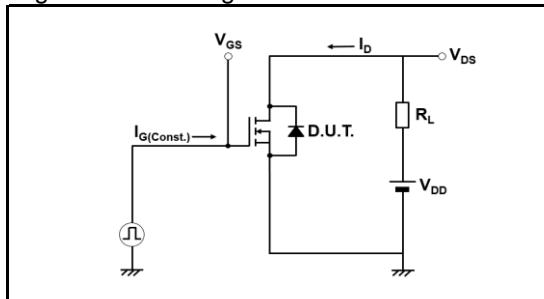


Fig.2-1 Switching Characteristics Measurement Circuit

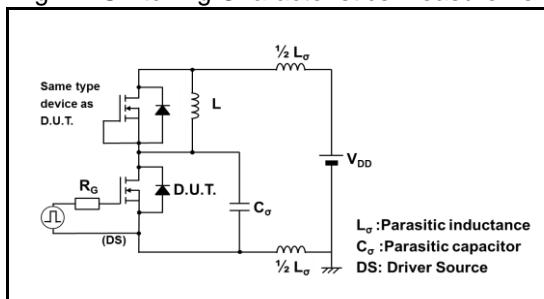


Fig.2-2 Waveforms for Switching Time

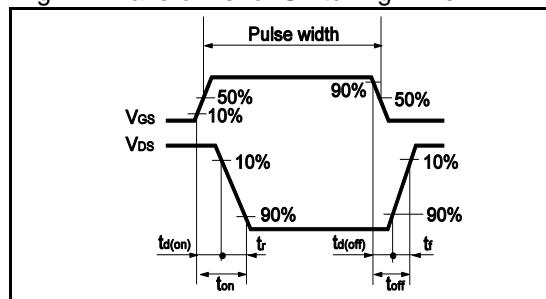


Fig.2-3 Waveforms for Switching Energy Loss

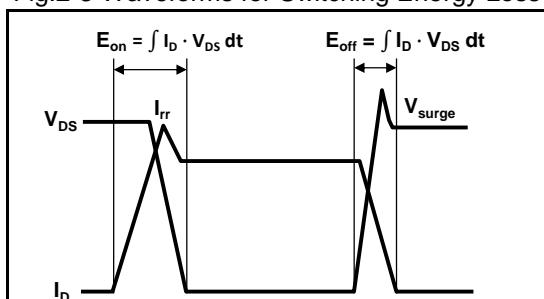


Fig.3-1 Reverse Recovery Time Measurement Circuit

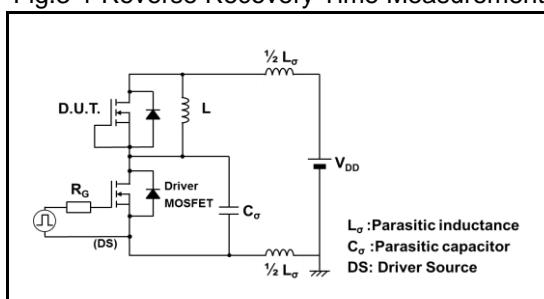
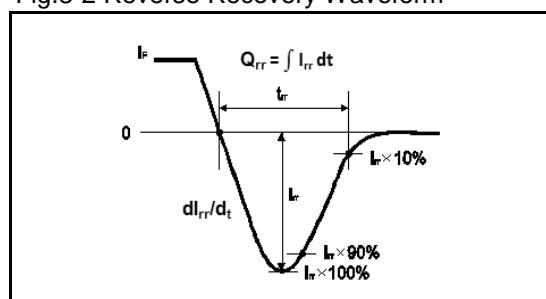
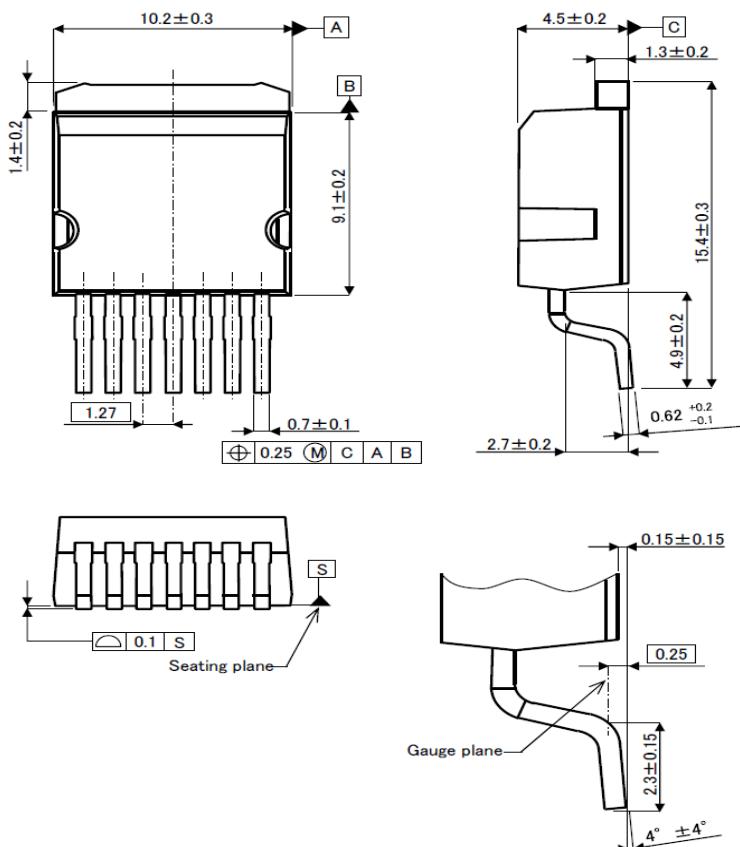


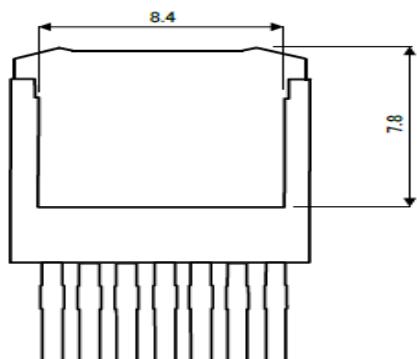
Fig.3-2 Reverse Recovery Waveform



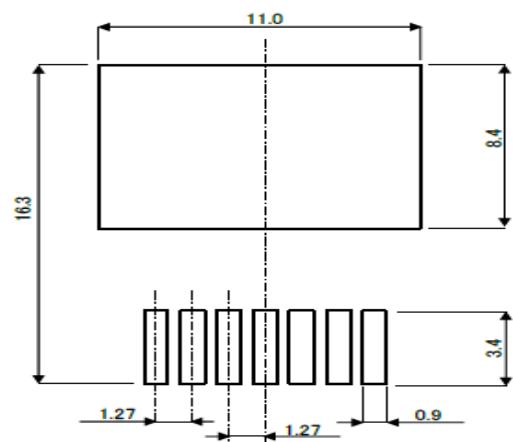
### ● Package Dimensions



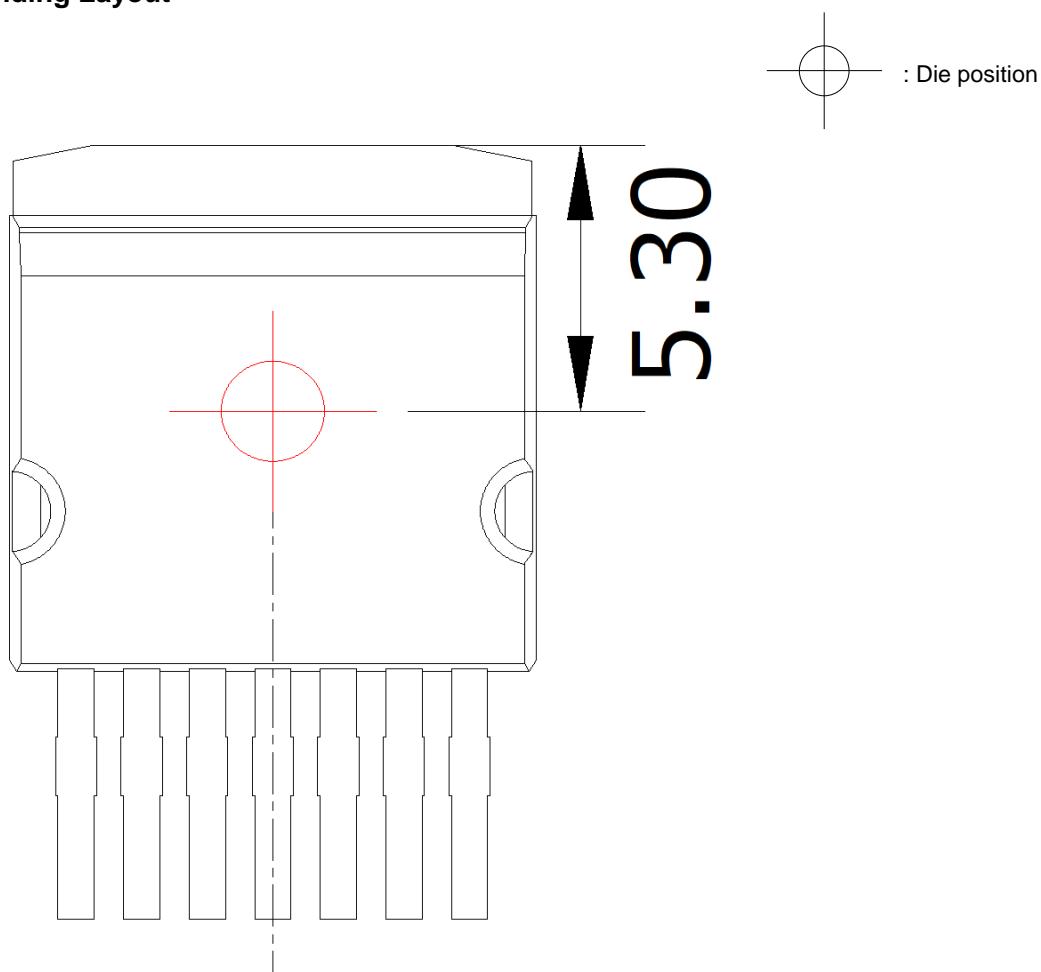
Unit: mm



## RECOMMENDED FOOTPRINT DIMENSIONS



Unit: mm

**●Die Bonding Layout**

- Front view of the packaging.
- Dimensions are design values.
- If the heat sink is to be installed, it should be in contact with the die bonding point.

Unit: mm

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